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Docket: 740756-2395

J1036 U.S. PTO
09/987607
11/15/01

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Divisional Patent Application of)
Hongyong ZHANG)
Based On Serial No. 09/110,895) Art Unit: 2826
Which Was Filed: July 7, 1998) Examiner: F. Abraham
For: METHOD FOR PRODUCING A)
SEMICONDUCTOR INTEGRATED)
CIRCUIT INCLUDING A THIN FILM)
TRANSISTOR AND A CAPACITOR) Date: November 15, 2001

INFORMATION DISCLOSURE STATEMENT

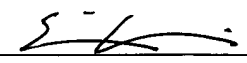
Honorable Commissioner for Patents and Trademarks
Washington, D.C. 20231

Sir:

In accordance with the provisions of 37 C.F.R. 1.56 and 37 C.F.R. 1.97-1.99, it is requested that the references listed on the attached Form PTO-1449 be made of record in the above-identified application.

The references listed on the attached Form PTO-1449 were cited in parent application Serial No. 09/110,895 filed July 7, 1998, and its predecessor application Serial No. 08/585,916.

Respectfully submitted,


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